

1. General Description

The EM74LV1T04 is a single, level translating inverting buffer. The low threshold inputs support 1.8 V input logic at $V_{CC} = 3.3$ V and can be used in 1.8 V to 3.3 V level up translation. In addition, the 5 V tolerant input pins enable level down translation (3.3 V to 2.5 V output at $V_{CC} = 2.5$ V). The output level is referenced to the supply voltage and supports 1.8 V, 2.5 V, 3.3 V and 5.0 V CMOS levels. The wide V_{CC} range permits the generation of output levels to connect to controllers or processors.

2. Features and Benefits

■ Single supply voltage translator at 1.8 V, 2.5 V, 3.3 V and 5.0 V

■ Up translation

- 1.2 V to 1.8 V at $V_{CC} = 1.8$ V
- 1.5 V to 2.5 V at $V_{CC} = 2.5$ V
- 1.8 V to 3.3 V at $V_{CC} = 3.3$ V
- 3.3 V to 5.0 V at $V_{CC} = 5.0$ V

■ Down translation

- 3.3 V to 1.8 V at $V_{CC} = 1.8$ V
- 3.3 V to 2.5 V at $V_{CC} = 2.5$ V
- 5.0 V to 3.3 V at $V_{CC} = 3.3$ V

■ 5 V tolerant inputs

■ Latch-up performance exceeds 200 mA

■ ESD protection:

- HBM ANSI/ESDA/JEDEC JS-001 Class 3A exceeds 6000 V
- CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V

■ Multiple package options

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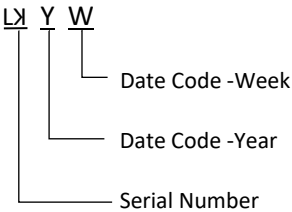
3. Ordering Information

Table 1. Ordering information

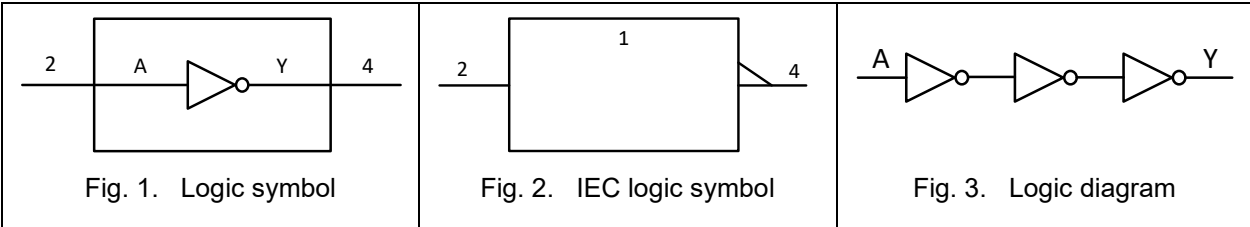
Type number	Topside marking	Package		
		Name	Description	Quantity
EM74LV1T04GV	LXYW	SOT23-5L	SOT23 package, 5 pins 2.92 mm × 1.6 mm; 1.25 mm (Max) height	3000
EM74LV1T04GW	LXYW	SOT353	SOT353 package, 5 pins 2.1 mm × 1.25 mm; 1.1 mm (Max) height	3000
EM74LV1T04GX	LX	DFN0.8x0.8-5L	DFN0.8x0.8 package, 5pins	3000

MARKING INFORMATION

NOTE: YW = Date Code.

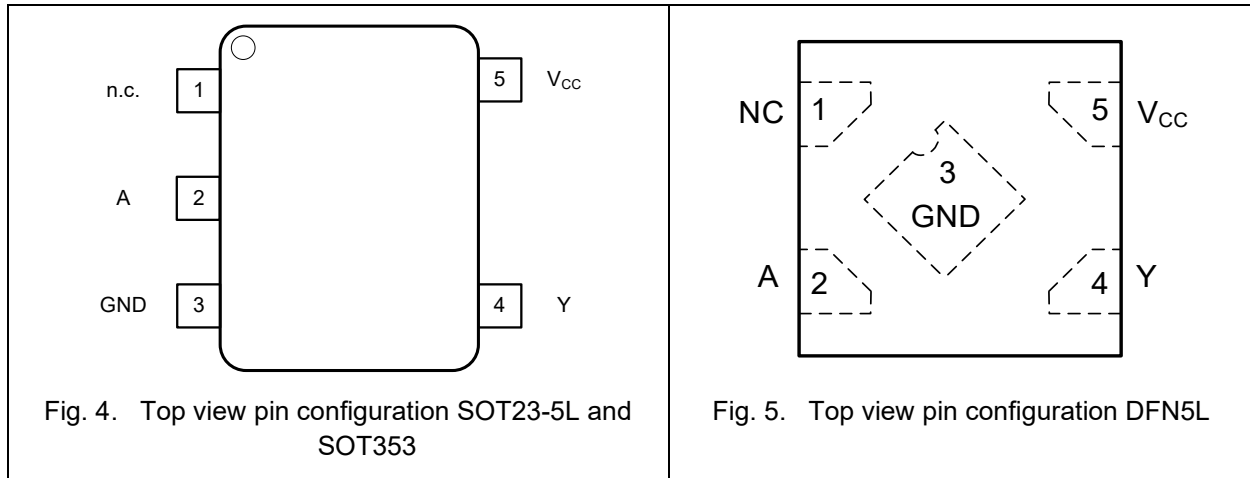


4. Function Diagram



5. Pinning Information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
n.c.	1	Not connected
A	2	Data input
GND	3	Ground (0V)
Y	4	Data output
V _{CC}	5	Supply voltage

6. Functional Description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
A	Y
L	H
H	L

7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Table 4. Absolute Maximum Ratings

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	7.0	V
V_I	input voltage	[1]	-0.5	7.0	V
V_O	output voltage	output HIGH or LOW [2][3]	-0.5	$V_{CC} + 0.5$	V
		output in power-off state [2]	-0.5	4.6	V
I_{IK}	input clamping current	$V_I < -0.5$ V	-20		mA
I_{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V		± 20	mA
I_O	output current	-0.5 V $< V_O < V_{CC} + 0.5$ V		± 25	mA
I_{CC}	supply current			50	mA
I_{GND}	ground current		-50		mA
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to $+125$ °C		250	mW
T_{stg}	storage temperature		-65	150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] If the output current ratings are observed, the output voltage ratings may be exceeded.

[3] This value is limited to 7 V maximum.

8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

Table 5. Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.6	5.0	5.5	V
V_I	input voltage		0		5.5	V
V_O	output voltage		0		V_{CC}	V
T_{amb}	ambient temperature		-40	25	125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.8$ V to 5.0 V			20	ns/V

9.Static Characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.8 \text{ V}$	1.0			1.0		V
		$V_{CC} = 2.0 \text{ V}$	1.03			1.03		V
		$V_{CC} = 2.25 \text{ V to } 2.5 \text{ V}$	1.18			1.18		V
		$V_{CC} = 2.75 \text{ V}$	1.25			1.25		V
		$V_{CC} = 3.0 \text{ V to } 3.3 \text{ V}$	1.41			1.41		V
		$V_{CC} = 3.6 \text{ V}$	1.49			1.49		V
		$V_{CC} = 4.5 \text{ V to } 5.0 \text{ V}$	2.03			2.03		V
		$V_{CC} = 5.5 \text{ V}$	2.11			2.11		V
V_{IL}	LOW-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.8 \text{ V}$			0.49		0.49	V
		$V_{CC} = 2.0 \text{ V}$			0.55		0.55	V
		$V_{CC} = 2.25 \text{ V to } 2.5 \text{ V}$			0.67		0.67	V
		$V_{CC} = 2.75 \text{ V}$			0.71		0.71	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$			0.75		0.75	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			0.80		0.80	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$						
		$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V};$ $I_O = -20 \mu\text{A};$	$V_{CC}-0.1$			$V_{CC}-0.1$		V
		$V_{CC} = 1.65 \text{ V}; I_O = -2 \text{ mA}$	1.21			1.21		V
		$V_{CC} = 1.8 \text{ V}; I_O = -2 \text{ mA}$	1.45			1.45		V
		$V_{CC} = 2.3 \text{ V}; I_O = -2.3 \text{ mA}$	2.0			2.0		V
		$V_{CC} = 2.3 \text{ V}; I_O = -3 \text{ mA}$	1.93			1.93		V
		$V_{CC} = 2.5 \text{ V}; I_O = -3 \text{ mA}$	2.15			2.15		V
		$V_{CC} = 3.0 \text{ V}; I_O = -3 \text{ mA}$	2.7			2.7		V
		$V_{CC} = 3.0 \text{ V}; I_O = -5.5 \text{ mA}$	2.49			2.49		V
		$V_{CC} = 3.3 \text{ V}; I_O = -5.5 \text{ mA}$	2.8			2.8		V
		$V_{CC} = 4.5 \text{ V}; I_O = -4 \text{ mA}$	4.1			4.1		V
		$V_{CC} = 4.5 \text{ V}; I_O = -8 \text{ mA}$	3.95			3.95		V
		$V_{CC} = 5.0 \text{ V}; I_O = -8 \text{ mA}$	4.5			4.5		V

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Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}						
		V _{CC} = 1.65 V to 5.5V; I _O = 20 µA;			0.1		0.1	V
		V _{CC} = 1.65 V; I _O = 2 mA			0.25		0.25	V
		V _{CC} = 2.3 V; I _O = 2.3 mA			0.15		0.15	V
		V _{CC} = 2.3 V; I _O = 3 mA			0.2		0.2	V
		V _{CC} = 3.0 V; I _O = 3 mA			0.15		0.15	V
		V _{CC} = 3.0 V; I _O = 5.5 mA			0.252		0.252	V
		V _{CC} = 4.5 V; I _O = 4 mA			0.2		0.2	V
		V _{CC} = 4.5 V; I _O = 8 mA			0.35		0.35	V
I _I	input leakage current	V _I = V _{CC} or GND ; V _{CC} = 0 V to 5.5 V			±1.0		±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND ; I _O = 0 A ; V _{CC} = 1.8 V, 2.5 V, 3.3 V, 5.0 V			10		10	µA
ΔI _{CC}	additional supply current	per input pin; V _{CC} = 1.8 V; V _I = 0.3 V or 1.1 V; I _O = 0 A; other pins at V _{CC} or GND			10		10	µA
		per input pin; V _{CC} = 5.5 V; V _I = 0.3 V or 3.4 V; I _O = 0 A; other pins at V _{CC} or GND			1.5		1.5	mA
C _I	input capacitance	V _I = V _{CC} or GND; V _{CC} = 3.3 V		2.6				pF
C _O	output capacitance	V _O = V _{CC} or GND; V _{CC} = 3.3 V		3.2				pF

[1]All typical values are measured at T_{amb} = 25°C.

10. Dynamic Characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	A, B to Y; see Fig. 6 [2]						
		$V_{CC} = 1.8 \text{ V}$, $C_L = 15 \text{ pF}$		13.6	20.5		21.2	ns
		$V_{CC} = 2.5 \text{ V}$, $C_L = 15 \text{ pF}$		5.6	11.0		12.0	ns
		$V_{CC} = 3.3 \text{ V}$, $C_L = 15 \text{ pF}$		3.7	7.5		8.0	ns
		$V_{CC} = 5.0 \text{ V}$, $C_L = 15 \text{ pF}$		2.9	7.0		7.5	ns
C_{PD}	power dissipation capacitance	$C_L = 15 \text{ pF}$; $f = 10 \text{ MHz}$; $V_I = \text{GND to } V_{CC}$; [3]						
		$V_{CC} = 1.8 \text{ V}$		10.6				pF
		$V_{CC} = 2.5 \text{ V}$		11.7				pF
		$V_{CC} = 3.3 \text{ V}$		12.7				pF
		$V_{CC} = 5.0 \text{ V}$		15.2				pF

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

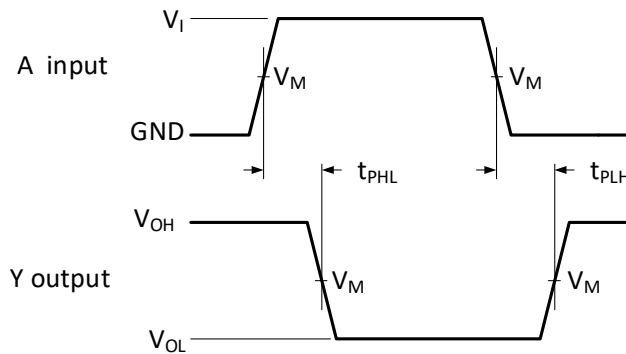
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

10.1. Waveforms and test circuit



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. The input A to output Y propagation delays

Table 8. Measurement points

Input	Output
V_M	V_M
$0.5 \times V_I$	$0.5 \times V_{CC}$

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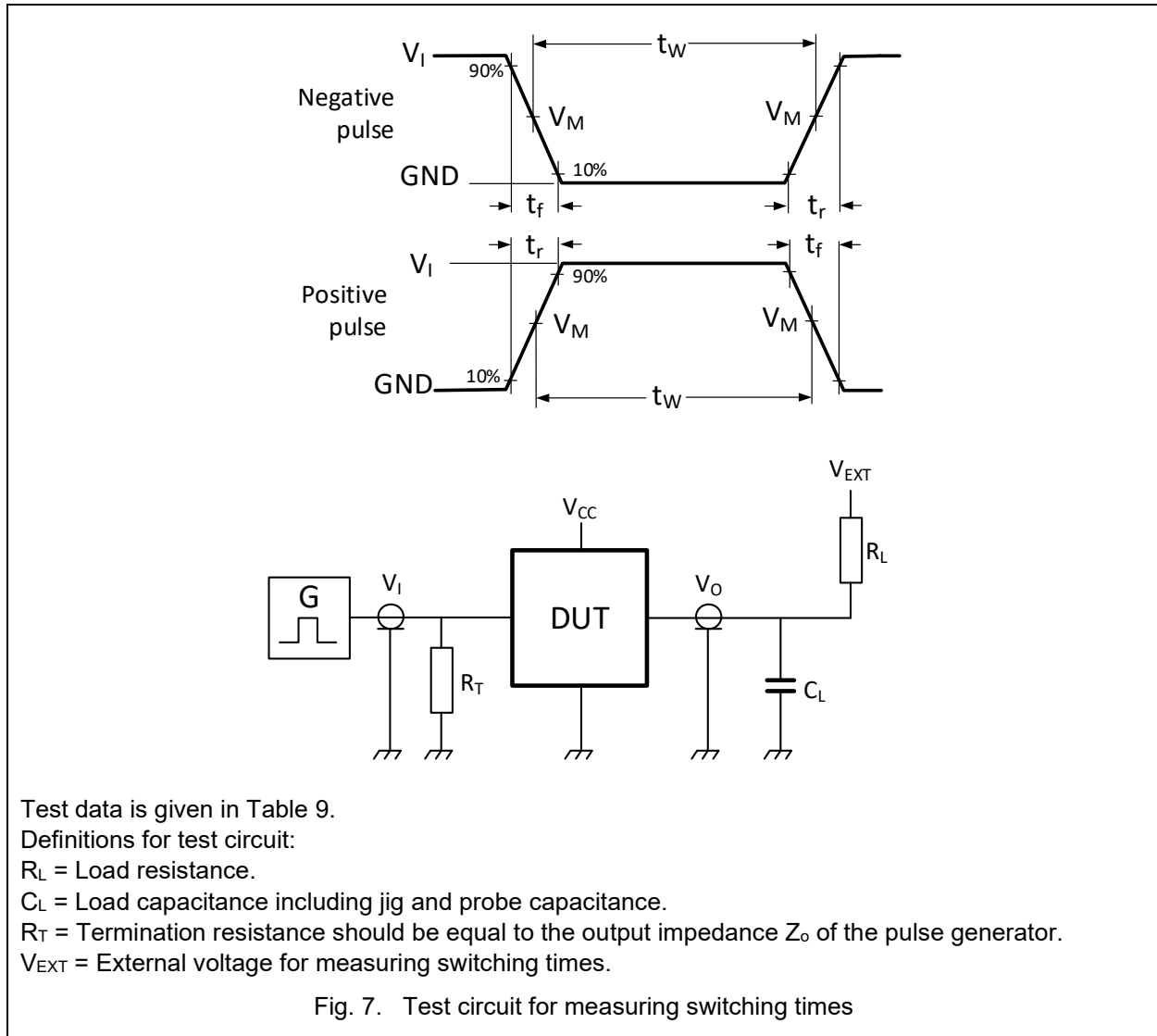
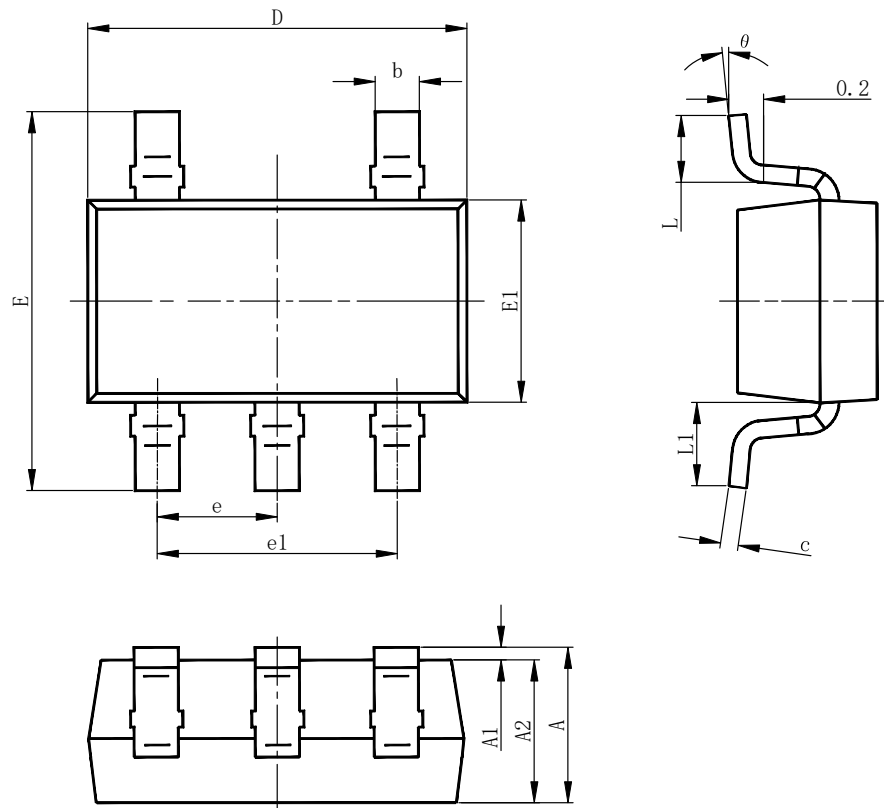


Table 9. Test data

Supply voltage	Input			Load		V_{EXT}		
V_{CC}	V_I	$t_r = t_f$	f_{max}	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
1.8 V	V_{CC}	≤ 2.5 ns	15MHz	15 pF	1 k Ω	open	GND	V_{CC}
2.5 V	V_{CC}	≤ 2.5 ns	25MHz	15 pF	1 k Ω	open	GND	V_{CC}
3.3 V	3 V	≤ 2.5 ns	50MHz	15 pF	1 k Ω	open	GND	V_{CC}
5.0 V	3 V	≤ 2.5 ns	50MHz	15 pF	1 k Ω	open	GND	V_{CC}

11. Package Outline

SOT23-5L

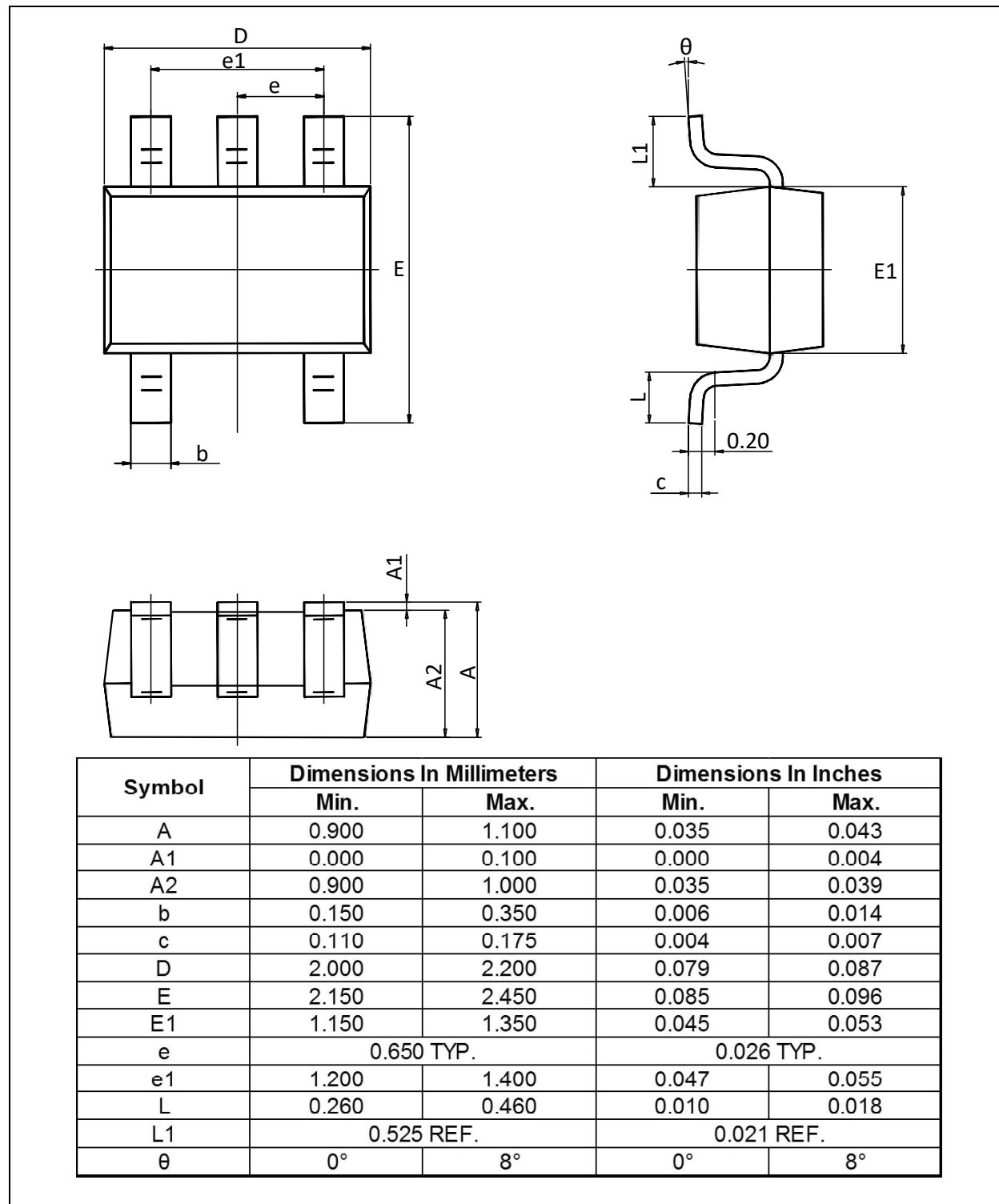


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
L1	0.600REF.		0.024REF.	
θ	0°	8°	0°	8°

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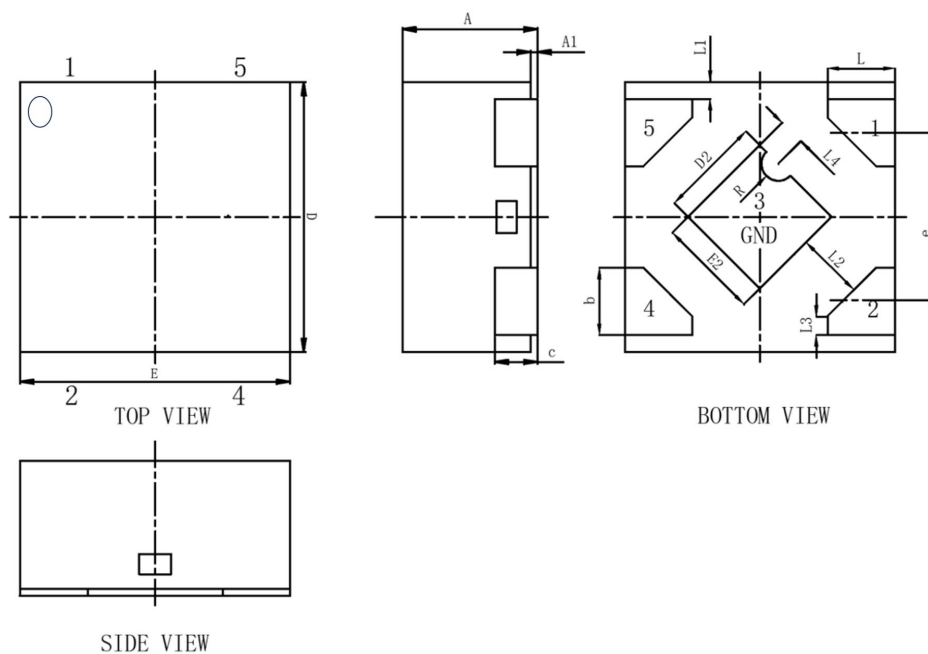
SOT353



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DFN0.8x0.8-4L

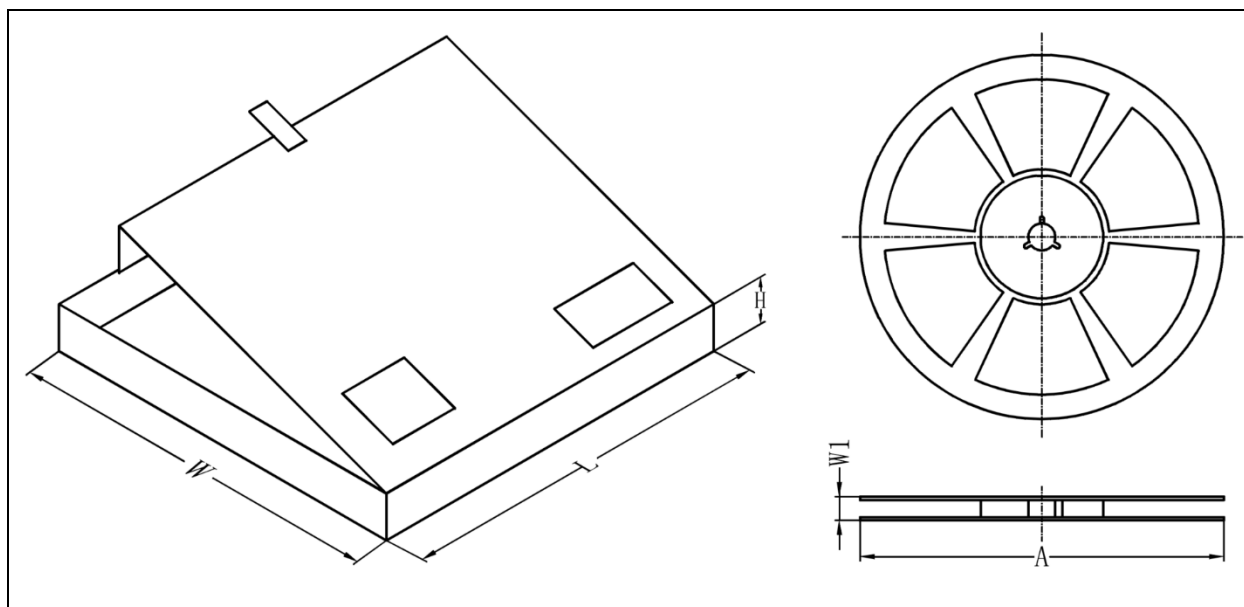


SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.35	—	0.40
A1	0.00	0.02	0.05
b	0.15	0.20	0.25
c	0.127REF		
D	0.75	0.80	0.85
D2	0.20	0.30	0.40
e	0.50BSC		
E	0.75	0.80	0.85
E2	0.20	0.30	0.40
L	0.15	0.20	0.25
L1	0.05REF		
L2	0.20REF		
L3	0.055REF		
L4	0.10REF		
R	0.05REF		

Technical drawing illustrating a multi-pass turning operation on a lathe. The main view shows a cylindrical workpiece with four passes (P0, A0, P1) and a central section divided into four quadrants (Q1, Q2, Q3, Q4). Dimensions include width W, pass widths P0, A0, P1, and quadrant width B0. A side view shows the tool with thickness T and width K. An arrow indicates the "Direction of feed".

Package version	Type number ending	A0(mm)	B0(mm)	K(mm)	T(mm)	P1(mm)	W(mm)	P0(mm)	PIN 1
DFN0.8x0.8-5L	GX	0.91	0.91	0.5	0.2	2	8	4	Q1
SOT353	GW	2.55	2.55	1.2	0.2	4	8	4	Q3
SOT23-5L	GV	3.23	3.17	1.37	0.25	4	8	4	Q3

12.2. Reel and box dimensions


Table 11. Dimensions and quantities

Package version	Reel Dimension A (mm)	Max Reel Width W1 (mm)	SPQ (pcs)[1]	Reels per box	Outer box dimensions L×W×H(mm)[2]
DFN0.8x0.8-5L	180	13.2	3000	1	210x200x40
SOT353	180	13.2	3000	1	210x200x40
SOT23-5L	180	13.2	3000	1	210x200x40

[1] Packing quantity dependent on specific product type. Please contact your local Energymath representative for ordering.

[2] Dimensions for reference only.

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
CDM	Charged Device Model

14. Revision History

Table 13. Revision history

Document ID	Release Date	Data sheet status	Change notice	Supersedes
EM74LV1T04 Rev. 1.0	Mar 10, 2026	Product datasheet		